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## In the Specification:

Please amend the paragraph beginning on page 12, line 7 as follows:

First, the silicon substrate 15 shown in Figs. 5A through 5C is prepared. In this silicon substrate 15, anisopropic anisotropic etching is performed on the upper surface of the substrate consisting of silicon single crystal, thereby forming a substantially V-shaped (trapezoidal) first groove portion 15b. The inclination angle ( $\theta$ 1,  $\theta$ 2, and  $\theta$ 3) of the first through third inclined surfaces 15e, 15f and 15g are all 54.7 degrees.